



**THE DATASHEET OF
TLV2621IDBVR**

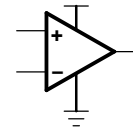


FAMILY OF LOW-POWER WIDE BANDWIDTH SINGLE SUPPLY OPERATIONAL AMPLIFIERS WITH SHUTDOWN

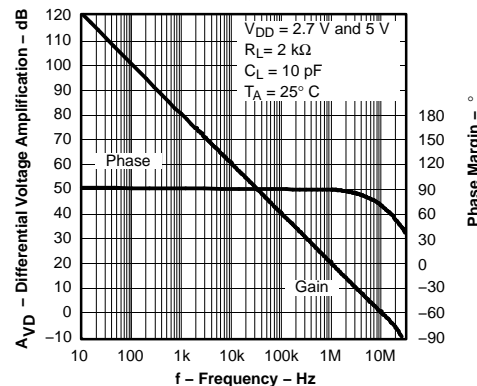
FEATURES

- CMOS Rail-To-Rail Output
- V_{ICR} Includes Positive Rail
- Wide Bandwidth . . . 11 MHz
- Slew Rate . . . 10 V/ μ s
- Supply Current . . . 800 μ A/Channel
- Input Noise Voltage . . . 27 nV/ $\sqrt{\text{Hz}}$
- Ultralow Power-Down Mode:
 $I_{DD(\text{SHDN})} = 4 \mu\text{A/Channel}$
- Supply Voltage Range . . . 2.7 V to 5.5 V
- Specified Temperature Range:
-40°C to 125°C . . . Industrial Grade
- Ultrasmall Packaging:
5 or 6 Pin SOT-23 (TLV2620/1)
8 or 10 Pin MSOP (TLV2622/3)
- Universal Opamp EVM (See SLOU060 for More Information)

Operational Amplifier



DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE
vs
FREQUENCY



DESCRIPTION

The TLV262x single supply operational amplifiers provide rail-to-rail output with an input range that includes the positive rail. The TLV262x takes the minimum operating supply voltage down to 2.7 V over the extended industrial temperature range (-40°C to 125°C) while adding the rail-to-rail output swing feature. The TLV262x also provides 11-MHz bandwidth from only 800 μ A of supply current. The maximum recommended supply voltage is 5.5 V, which, when coupled with a 2.7-V minimum, allows the devices to be operated from lithium ion cells. The combination of wide bandwidth, low noise, and low distortion makes it ideal for high speed and high resolution data converter applications. The positive input range allows it to directly interface to positive rail referred systems. All members are available in PDIP and SOIC with the singles in the small SOT-23 package, duals in the MSOP, and quads in the TSSOP package.

The 2.7-V operation makes it compatible with Li-Ion powered systems and the operating supply voltage range of many micro-power micro-controllers available today including TI's MSP430.

AMPLIFIER SELECTION TABLE

DEVICE	V_{DD} [V]	$I_{DD/\text{ch}}$ [μ A]	V_{IO} [μ V]	I_{IB} [μ A]	V_{ICR} [V]	GBW [MHz]	SLEW RATE [V/ μ s]	V_n , 1 kHz [nV/ $\sqrt{\text{Hz}}$]	I_o [mA]	SHUT-DOWN
TLV262x	2.7-5.5	750	250	1	1 V to $V_{DD} + 0.2$	11	10	27	28	Y
TLV263x	2.7-5.5	750	250	1	GND to $V_{DD} - 0.8$	10	9	27	28	Y
TLV278x	1.8-3.6	650	250	2.5	-0.2 to $V_{DD} + 0.2$	8	5	9	10	Y
TLC07x	4.5 - 16	1900	60	1.5	0.5 to $V_{DD} - 0.8$	10	19	7	55	Y
TLC08x	4.5 - 16	1900	60	3	GND to $V_{DD} - 1$	10	19	8.5	55	Y



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

TLV2620 AND TLV2621 AVAILABLE OPTIONS⁽¹⁾

T _A	V _{IO} max AT 25°C	PACKAGED DEVICES			
		SMALL OUTLINE (D) ⁽²⁾	SOT-23		PLASTIC DIP (P)
			(DBV) ⁽³⁾	SYMBOL	
-40°C to 125°C	3500 μV	TLV2620ID TLV2621ID	TLV2620IDBV TLV2621IDBV	VBAI VBBI	TLV2620IP TLV2621IP

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.
 (2) This package is available taped and reeled. To order this packaging option, add an **R** suffix to the part number (e.g., TLV2620IDR).
 (3) The SOT23 package devices are only available taped and reeled. The **R** Suffix denotes quantities (3,000 pieces per reel). For smaller quantities (250 pieces per mini-reel), add a **T** suffix to the part number (e.g. TLV2620IDBVT).

TLV2622 AND TLV2623 AVAILABLE OPTIONS⁽¹⁾

T _A	V _{IO} max AT 25°C	PACKAGED DEVICES						
		SMALL OUTLINE ⁽²⁾ (D)	MSOP				PLASTIC DIP (N)	PLASTIC DIP (P)
			(DGK) ⁽²⁾	SYMBOL	(DGS) ⁽²⁾	SYMBOL		
-40°C to 125°C	3500 μV	TLV2622ID TLV2623ID	TLV2622IDGK —	xxTIAKM —	— TLV2623IDGS	— xxTIALC	— TLV2623IN	TLV2622IP —

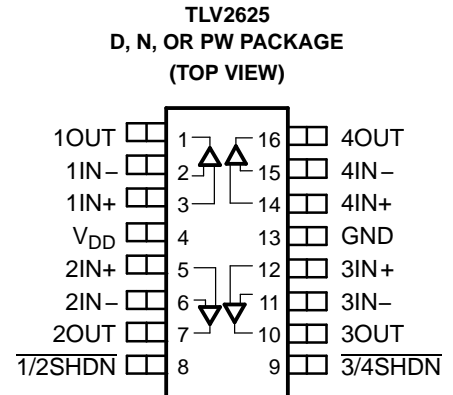
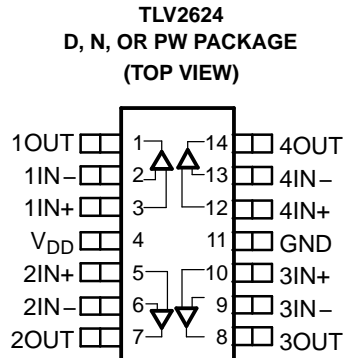
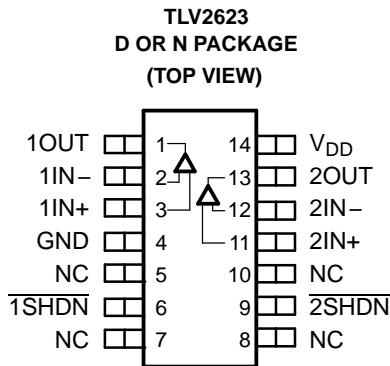
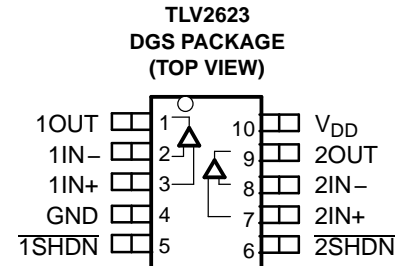
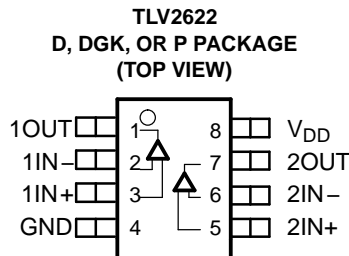
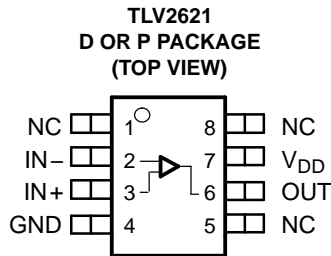
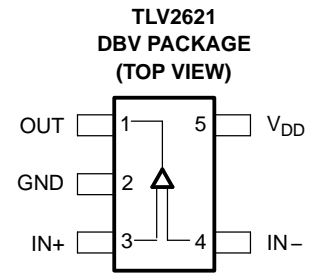
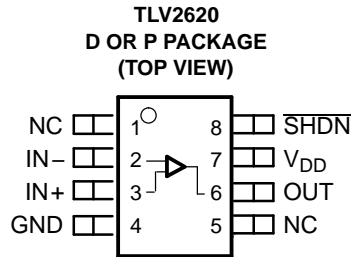
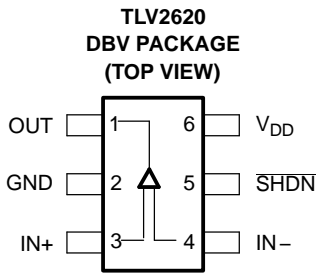
- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.
 (2) This package is available taped and reeled. To order this packaging option, add an **R** suffix to the part number (e.g., TLV2622IDR).

TLV2624 AND TLV2625 AVAILABLE OPTIONS⁽¹⁾

T _A	V _{IO} max AT 25°C	PACKAGED DEVICES		
		SMALL OUTLINE (D) ⁽²⁾	PLASTIC DIP (N)	TSSOP (PW)
-40°C to 125°C	3500 μV	TLV2624ID TLV2625ID	TLV2624IN TLV2625IN	TLV2624IPW TLV2625IPW

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.
 (2) This package is available taped and reeled. To order this packaging option, add an **R** suffix to the part number (e.g., TLV2624IDR).

TLV262X PACKAGE PINOUTS⁽¹⁾

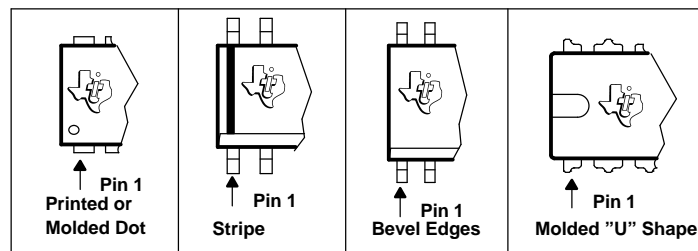


NC – No internal connection

$\overline{1/2SHDN}$ Pin (8) controls amplifiers 1 and 2.
 $\overline{3/4SHDN}$ Pin (9) controls amplifiers 3 and 4.

(1) SOT-23 may or may not be indicated.

TYPICAL PIN 1 INDICATORS



NOTE:

If there is not a Pin 1 indicator, turn device to enable reading the symbol from left to right. Pin 1 is at the lower left corner of the device.

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

V_{DD}	Supply voltage ⁽²⁾	6 V
V_{ID}	Differential input voltage	$\pm V_{DD}$
V_I	Input voltage range ⁽²⁾	+1 to $V_{DD} + 0.2$ V
I_I	Input current (any input)	± 10 mA
I_O	Output current	± 40 mA
	Continuous total power dissipation	See Dissipation Rating Table
T_A	Operating free-air temperature range: I-suffix	-40°C to 125°C
T_J	Maximum junction temperature	150°C
T_{stg}	Storage temperature range	-65°C to 150°C
	Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

- (1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values, except differential voltages, are with respect to GND.

DISSIPATION RATING TABLE

PACKAGE	θ_{JC} (°C/W)	θ_{JA} (°C/W)	$T_A \leq 25^\circ\text{C}$ POWER RATING	$T_A = 125^\circ\text{C}$ POWER RATING
D (8)	38.3	176	710 mW	142 mW
D (14)	26.9	122.3	1022 mW	204.4 mW
D (16)	25.7	114.7	1090 mW	218 mW
DBV (5)	55	324.1	385 mW	77.1 mW
DBV (6)	55	294.3	425 mW	85 mW
DGK (8)	54.2	259.9	481 mW	96.1 mW
DGS (10)	54.1	259.7	485 mW	97 mW
N (14, 16)	32	78	1600 mW	320.5 mW
P (8)	41	104	1200 mW	240.4 mW
PW (14)	29.3	173.6	720 mW	144 mW
PW (16)	28.7	161.4	774 mW	154.9 mW

RECOMMENDED OPERATING CONDITIONS

			MIN	MAX	UNIT
V_{DD}	Supply voltage	Single supply	2.7	5.5	V
		Split supply	± 1.35	± 2.75	
V_{ICR}	Common-mode input voltage range		1	$V_{DD} + 0.2$	V
T_A	Operating free-air temperature	I-suffix	-40	125	°C
	Shutdown on/off voltage level ⁽¹⁾	V_{IL}		0.4	V
		V_{IH}	2		

- (1) Relative to GND.

ELECTRICAL CHARACTERISTICS

at specified free-air temperature, $V_{DD} = 2.7\text{ V}, 5\text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		$T_A^{(1)}$	MIN	TYP	MAX	UNIT			
DC PERFORMANCE											
V_{IO}	Input offset voltage	$V_{IC} = V_{DD}/2, V_O = V_{DD}/2,$ $R_S = 50\ \Omega$		25°C	250	3500		μV			
				Full range		4500					
α_{VIO}	Temperature coefficient of input offset voltage			25°C		3		$\mu\text{V}/^\circ\text{C}$			
$CMRR$	Common-mode rejection ratio	$V_{IC} = 1\text{ to }V_{DD},$ $R_S = 50\ \Omega$		$V_{DD} = 2.7\text{ V}$		25°C	77	98	dB		
						Full range	63				
				$V_{DD} = 5\text{ V}$		25°C	78	99			
						Full range	75				
A_{VD}	Large-signal differential voltage amplification	$V_{DD} = 2.7\text{ V}, R_L = 2\text{ k}\Omega,$ $V_{O(PP)} = 1.7\text{ V}$		$V_{DD} = 2.7\text{ V}$		25°C	90	100	dB		
						Full range	82				
				$V_{DD} = 5\text{ V}, R_L = 2\text{ k}\Omega,$ $V_{O(PP)} = 4\text{ V}$		25°C	95	100			
						Full range	90				
INPUT CHARACTERISTICS											
I_{IO}	Input offset current	$V_{IC} = V_{DD}/2, V_O = V_{DD}/2,$ $R_S = 50\ \Omega$		25°C		2	50	pA			
				Full Range			100				
I_{IB}	Input bias current			25°C		2	50				
				Full Range			200				
$r_{i(d)}$	Differential input resistance			25°C		100		G Ω			
$C_{i(c)}$	Common-mode input capacitance	$f = 1\text{ kHz}$		25°C		8		pF			
OUTPUT CHARACTERISTICS											
V_{OH}	High-level output voltage	$V_{IC} = V_{DD}/2,$ $I_{OH} = -1\text{ mA}$		$V_{DD} = 2.7\text{ V}$		25°C	2.6	2.67	V		
						Full range	2.55				
				$V_{DD} = 5\text{ V}$		25°C	4.95	4.98			
						Full range	4.9				
		$V_{IC} = V_{DD}/2,$ $I_{OH} = -10\text{ mA}$		$V_{DD} = 2.7\text{ V}$		25°C	2.3	2.43			
						Full range	2.2				
				$V_{DD} = 5\text{ V}$		25°C	4.7	4.8			
						Full range	4.6				
V_{OL}	Low-level output voltage	$V_{IC} = V_{DD}/2,$ $I_{OL} = 1\text{ mA}$		$V_{DD} = 2.7\text{ V}$		25°C		0.03	0.1		
						Full range		0.15			
				$V_{DD} = 5\text{ V}$		25°C		0.025	0.05		
						Full range		0.1			
		$V_{IC} = V_{DD}/2,$ $I_{OL} = 10\text{ mA}$		$V_{DD} = 2.7\text{ V}$		25°C		0.26	0.4		
						Full range		0.45			
				$V_{DD} = 5\text{ V}$		25°C		0.2	0.25		
						Full range		0.35			
I_O	Output current	$V_{DD} = 2.7\text{ V},$ $V_O = 0.5\text{ V from rail}$		Sourcing		25°C			14		
								Sinking			19
										Sourcing	
								Sinking			
I_{OS}	Short-circuit output current			25°C							50
								Sourcing			95
										Sinking	

(1) Full range is -40°C to 125°C for the I-suffix.

ELECTRICAL CHARACTERISTICS (continued)

at specified free-air temperature, $V_{DD} = 2.7\text{ V}$, 5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		$T_A^{(1)}$	MIN	TYP	MAX	UNIT
POWER SUPPLY								
I_{DD}	Supply current (per channel)	$V_O = V_{DD}/2$,	$\overline{SHDN} = V_{DD}$	25°C	800	1000		μA
				Full range		1300		
PSRR	Supply voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	$V_{DD} = 2.7\text{ V}$ to 3.3 V , $V_{IC} = V_{DD}/2$	No load	25°C	80	98		dB
				Full range	75			
		25°C		75	90			
		Full range		70				
DYNAMIC PERFORMANCE								
UGBW	Unity gain bandwidth	$R_L = 2\text{ k}\Omega$, $C_L = 10\text{ pF}$		25°C		11		MHz
SR+	Positive slew rate at unity gain	$R_L = 2\text{ k}\Omega$, $C_L = 50\text{ pF}$		25°C	3.5	4.5		$\text{V}/\mu\text{s}$
				Full range	2.7			
				25°C	5.4	7		
				Full range	3.4			
SR-	Negative slew rate at unity gain	$R_L = 2\text{ k}\Omega$, $C_L = 50\text{ pF}$		25°C	2.7	5		$\text{V}/\mu\text{s}$
				Full range	2.3			
				25°C	4.5	6		
				Full range	3.2			
ϕ_m	Phase margin	$R_L = 2\text{ k}\Omega$, $C_L = 10\text{ pF}$		25°C	63°			dB
	Gain margin				8			
NOISE/DISTORTION PERFORMANCE								
THD + N	Total harmonic distortion plus noise	$V_{O(PP)} = V_{DD}/2$, $R_L = 2\text{ k}\Omega$, $f = 10\text{ kHz}$	$A_V = 1$	25°C	0.002%			
			$A_V = 10$		0.019%			
			$A_V = 100$		0.095%			
V_n	Equivalent input noise voltage	$f = 1\text{ kHz}$ $f = 10\text{ kHz}$		25°C	53		$\text{nV}/\sqrt{\text{Hz}}$	
					27			
I_n	Equivalent input noise current	$f = 1\text{ kHz}$		25°C	0.9		$\text{fA}/\sqrt{\text{Hz}}$	
SHUTDOWN CHARACTERISTICS								
$I_{DD(SHDN)}$	Supply current, per channel in shutdown mode (TLV2620, TLV2623, TLV2625)	$\overline{SHDN} = 0.4\text{ V}$		25°C	4	11		μA
				Full range		13		
$t_{(on)}$	Amplifier turnon time ⁽²⁾	$R_L = 2\text{ k}\Omega$		25°C	4.5		μs	
					1.5			
$t_{(off)}$	Amplifier turnoff time ⁽²⁾	$R_L = 2\text{ k}\Omega$		25°C	200		ns	

(2) Disable time and enable time are defined as the interval between application of the logic signal to \overline{SHDN} and the point at which the supply current has reached half its final value.

TYPICAL CHARACTERISTICS

TABLE OF GRAPHS

			FIGURE
V_{IO}	Input offset voltage	vs Common-mode input voltage	1, 2
CMRR	Common-mode rejection ratio	vs Frequency	3
V_{OH}	High-level output voltage	vs High-level output current	4, 6
V_{OL}	Low-level output voltage	vs Low-level output current	5, 7
I_{DD}	Supply current	vs Supply voltage	8
I_{DD}	Supply current	vs Free-air temperature	9
PSRR	Power supply rejection ratio	vs Frequency	10
A_{VD}	Differential voltage amplification & phase	vs Frequency	11
	Gain-bandwidth product	vs Free-air temperature	12
SR	Slew rate	vs Supply voltage	13
		vs Free-air temperature	14, 15
ϕ_m	Phase margin	vs Load capacitance	16
V_n	Equivalent input noise voltage	vs Frequency	17
	Voltage-follower large-signal pulse response		18
	Voltage-follower small-signal pulse response		19
	Crosstalk	vs Frequency	20
$I_{DD(SHDN)}$	Shutdown supply current	vs Free-air temperature	21
$I_{DD(SHDN)}$	Shutdown supply current	vs Supply voltage	22
$I_{DD(SHDN)}$	Shutdown supply current/output voltage	vs Time	23

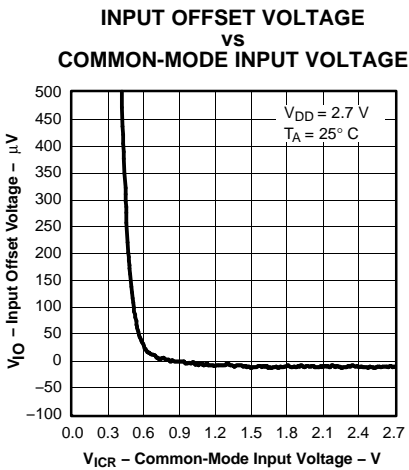


Figure 1.

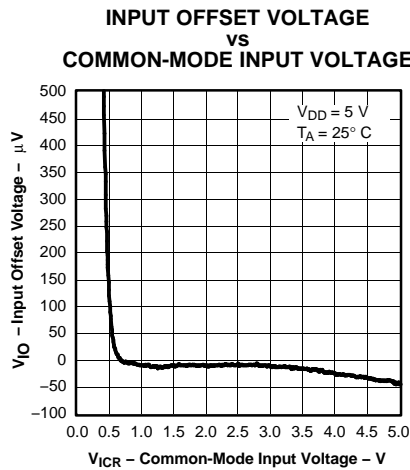


Figure 2.

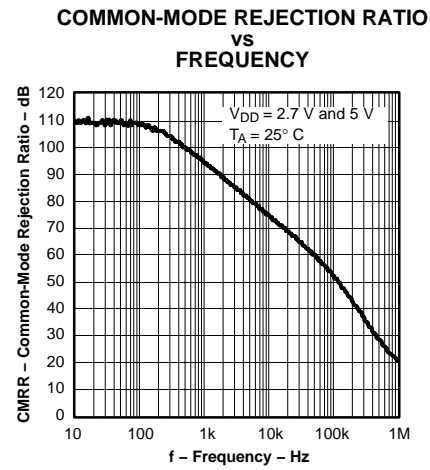


Figure 3.

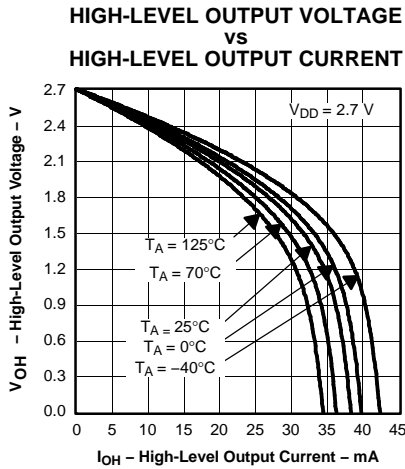


Figure 4.

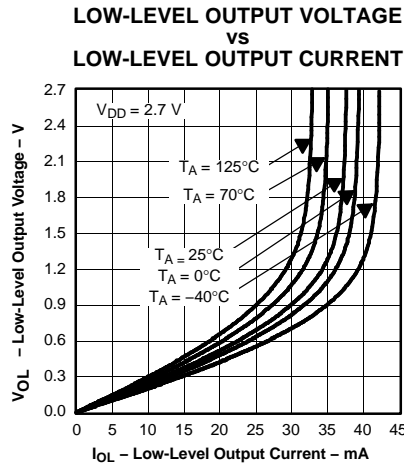


Figure 5.

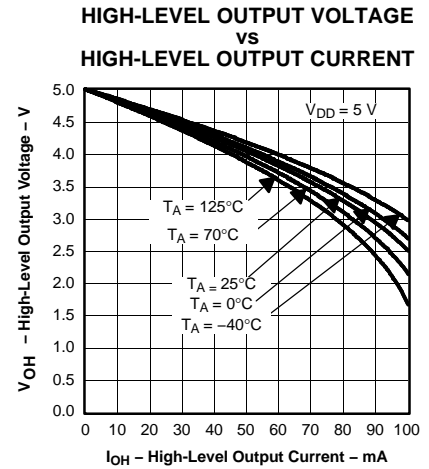


Figure 6.

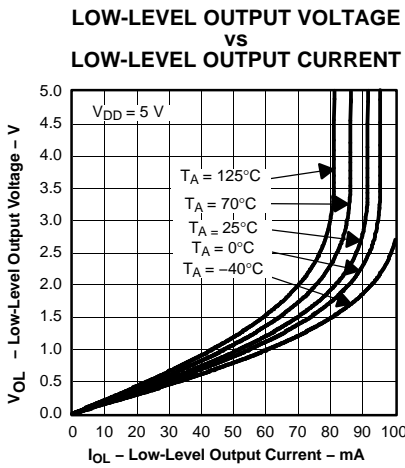


Figure 7.

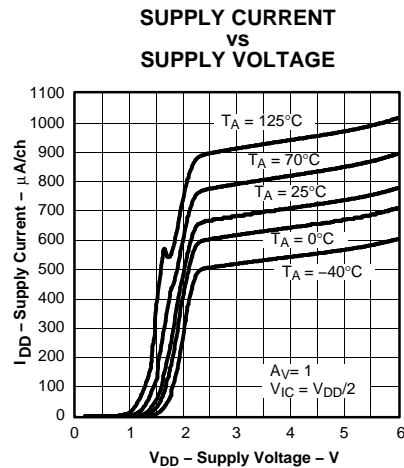


Figure 8.

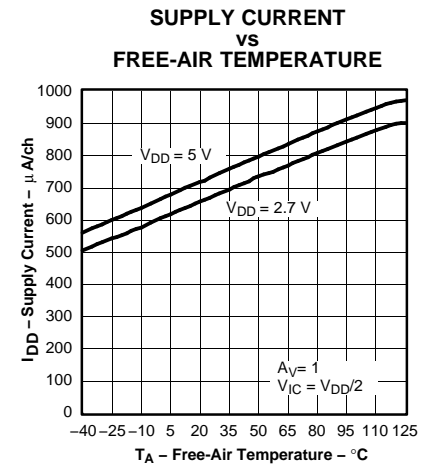


Figure 9.

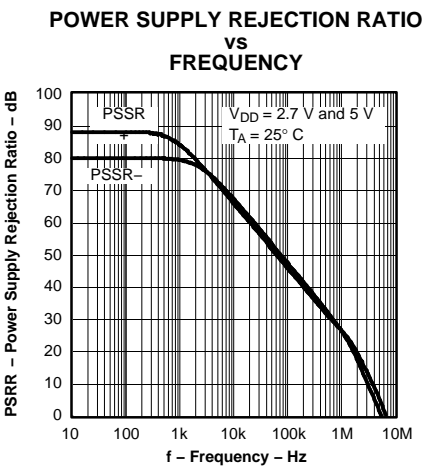


Figure 10.

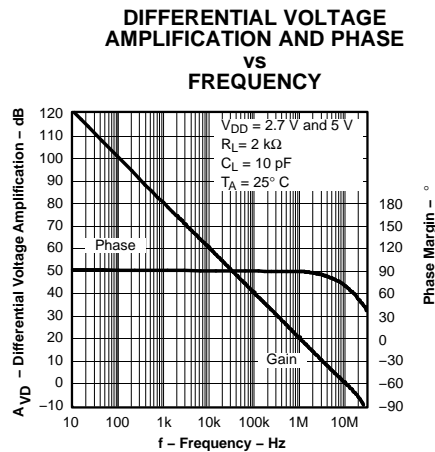


Figure 11.

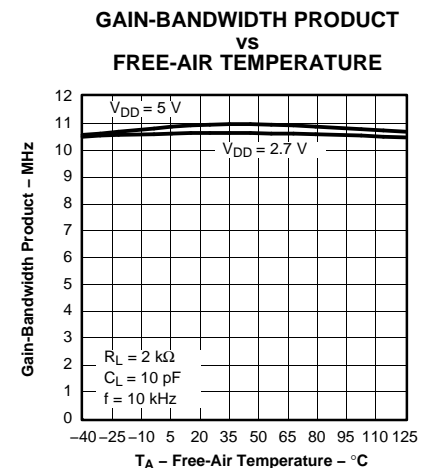


Figure 12.

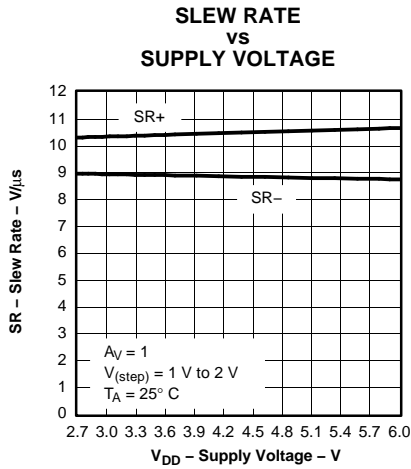


Figure 13.

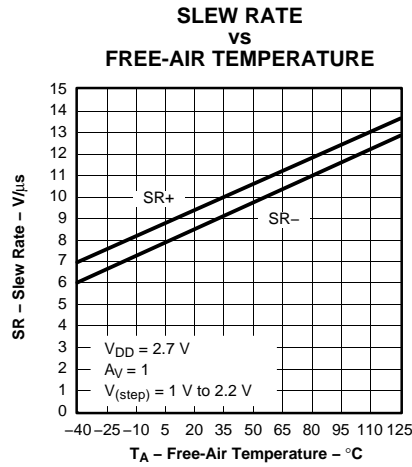


Figure 14.

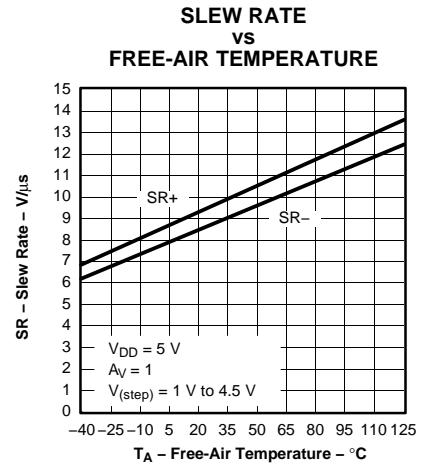


Figure 15.

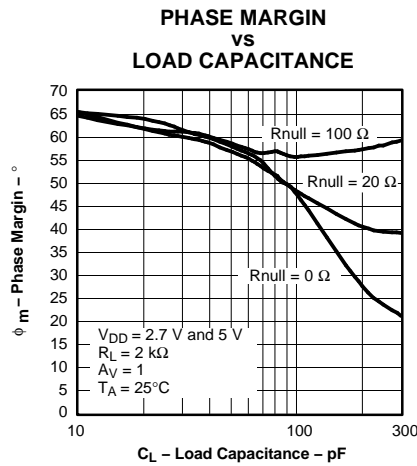


Figure 16.

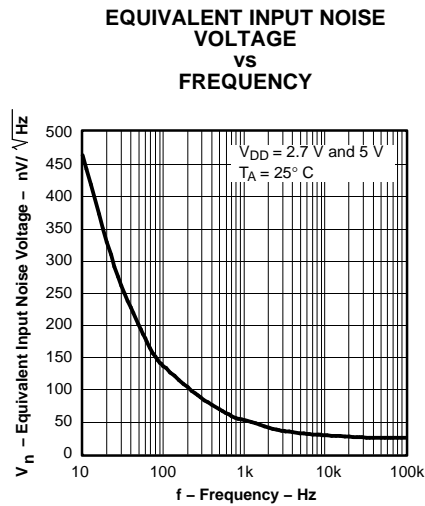


Figure 17.

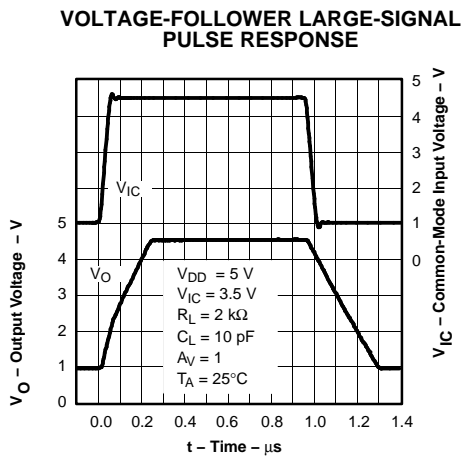


Figure 18.

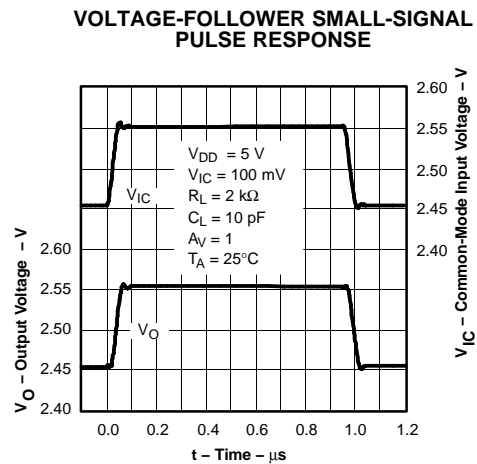


Figure 19.

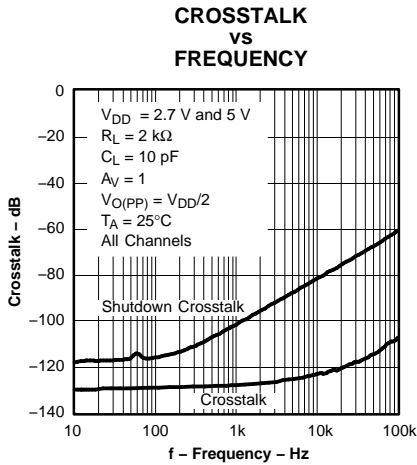


Figure 20.

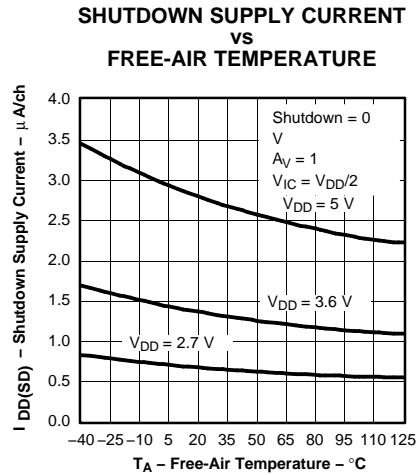


Figure 21.

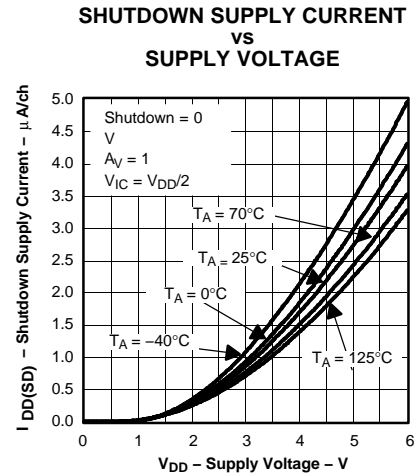


Figure 22.

**SHUTDOWN SUPPLY CURRENT/OUTPUT VOLTAGE
 vs
 TIME**

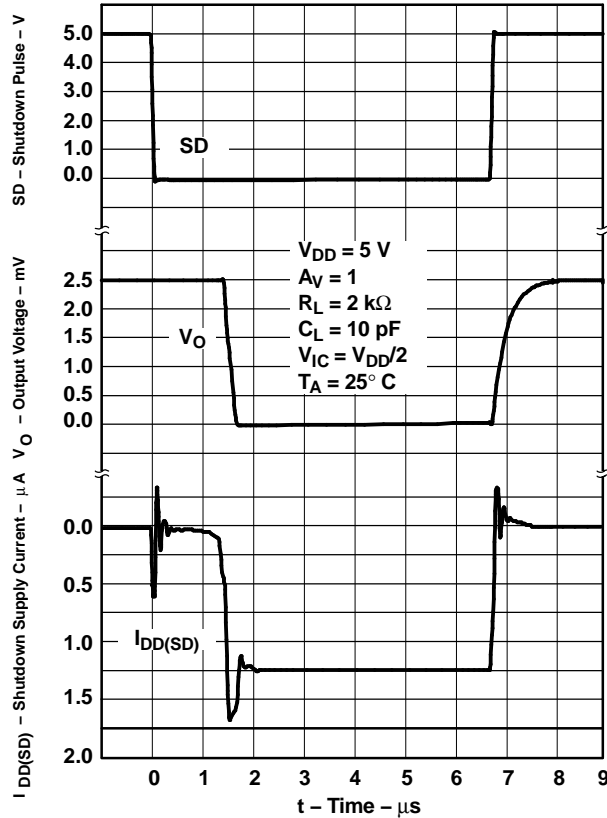


Figure 23.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TLV2620IDBVR	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VBAI	Samples
TLV2620IDBVT	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VBAI	Samples
TLV2620IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2620I	Samples
TLV2621IDBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VBBI	Samples
TLV2621IDBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VBBI	Samples
TLV2621IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2621I	Samples
TLV2622ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2622I	Samples
TLV2622IDGKR	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AKM	Samples
TLV2622IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2622I	Samples
TLV2623IDGS	ACTIVE	VSSOP	DGS	10	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	ALC	Samples
TLV2623IDGSR	ACTIVE	VSSOP	DGS	10	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	ALC	Samples
TLV2624ID	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2624I	Samples
TLV2624IDR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2624I	Samples
TLV2624IPW	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2624I	Samples
TLV2624IPWG4	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2624I	Samples
TLV2624IPWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	2624I	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of ≤ 1000 ppm threshold. Antimony trioxide based flame retardants must also meet the ≤ 1000 ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION



QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV2620IDBVR	SOT-23	DBV	6	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2620IDBVT	SOT-23	DBV	6	250	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2620IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2621IDBVR	SOT-23	DBV	5	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2621IDBVT	SOT-23	DBV	5	250	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2621IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2622IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2622IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2623IDGSR	VSSOP	DGS	10	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2624IDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLV2624IPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV2620IDBVR	SOT-23	DBV	6	3000	182.0	182.0	20.0
TLV2620IDBVT	SOT-23	DBV	6	250	182.0	182.0	20.0
TLV2620IDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2621IDBVR	SOT-23	DBV	5	3000	182.0	182.0	20.0
TLV2621IDBVT	SOT-23	DBV	5	250	182.0	182.0	20.0
TLV2621IDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2622IDGKR	VSSOP	DGK	8	2500	358.0	335.0	35.0
TLV2622IDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2623IDGSR	VSSOP	DGS	10	2500	358.0	335.0	35.0
TLV2624IDR	SOIC	D	14	2500	333.2	345.9	28.6
TLV2624IPWR	TSSOP	PW	14	2000	367.0	367.0	35.0

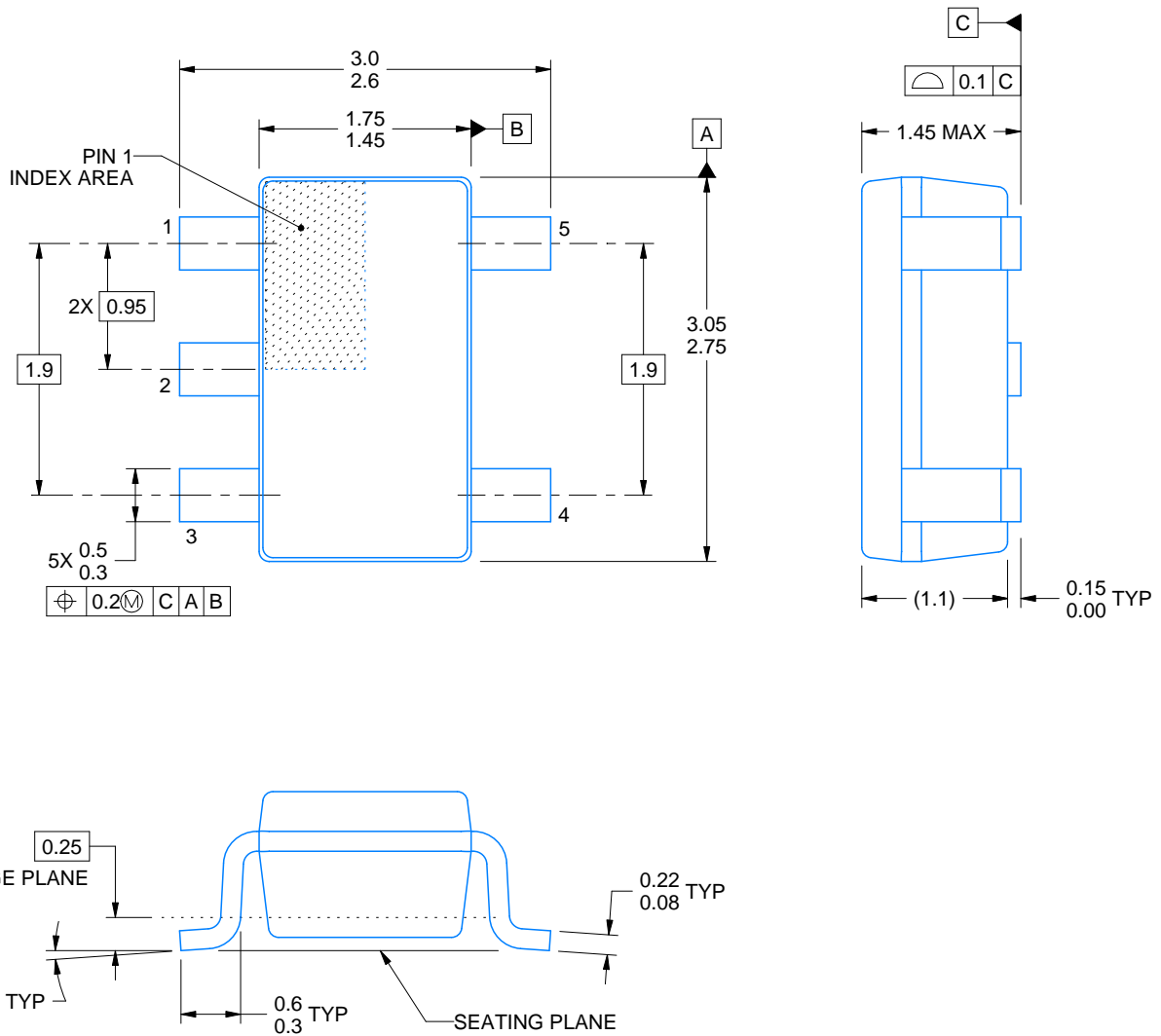
DBV0005A



PACKAGE OUTLINE

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



4214839/D 11/2018

NOTES:

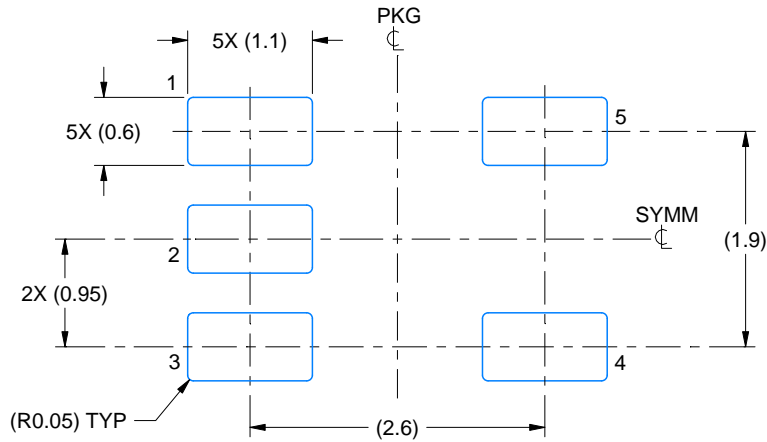
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-178.
4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.

EXAMPLE BOARD LAYOUT

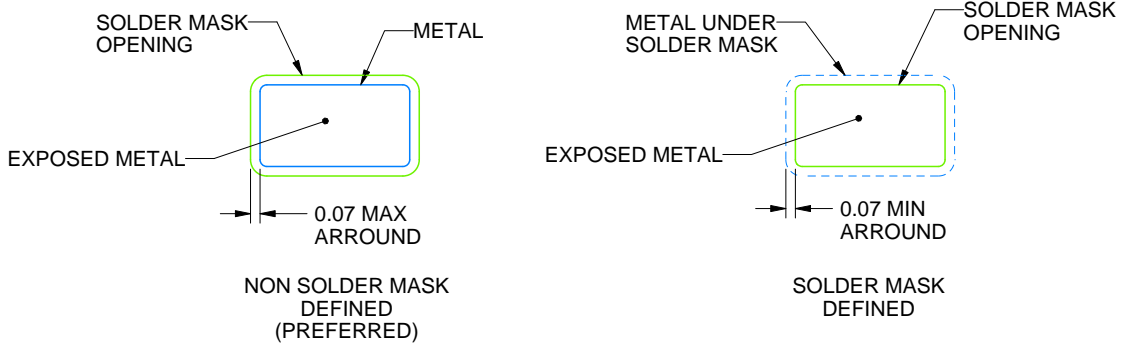
DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

4214839/D 11/2018

NOTES: (continued)

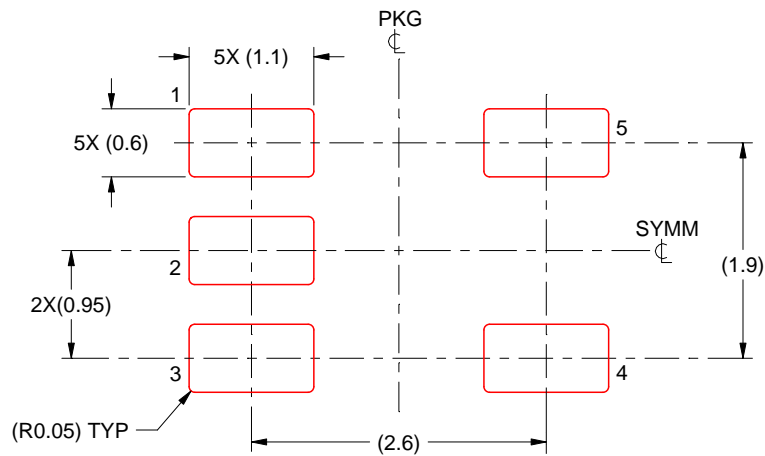
- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214839/D 11/2018

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
 - E. Falls within JEDEC MO-187 variation AA, except interlead flash.



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
 - Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
 - E. Reference JEDEC MS-012 variation AB.

D (R-PDSO-G14)

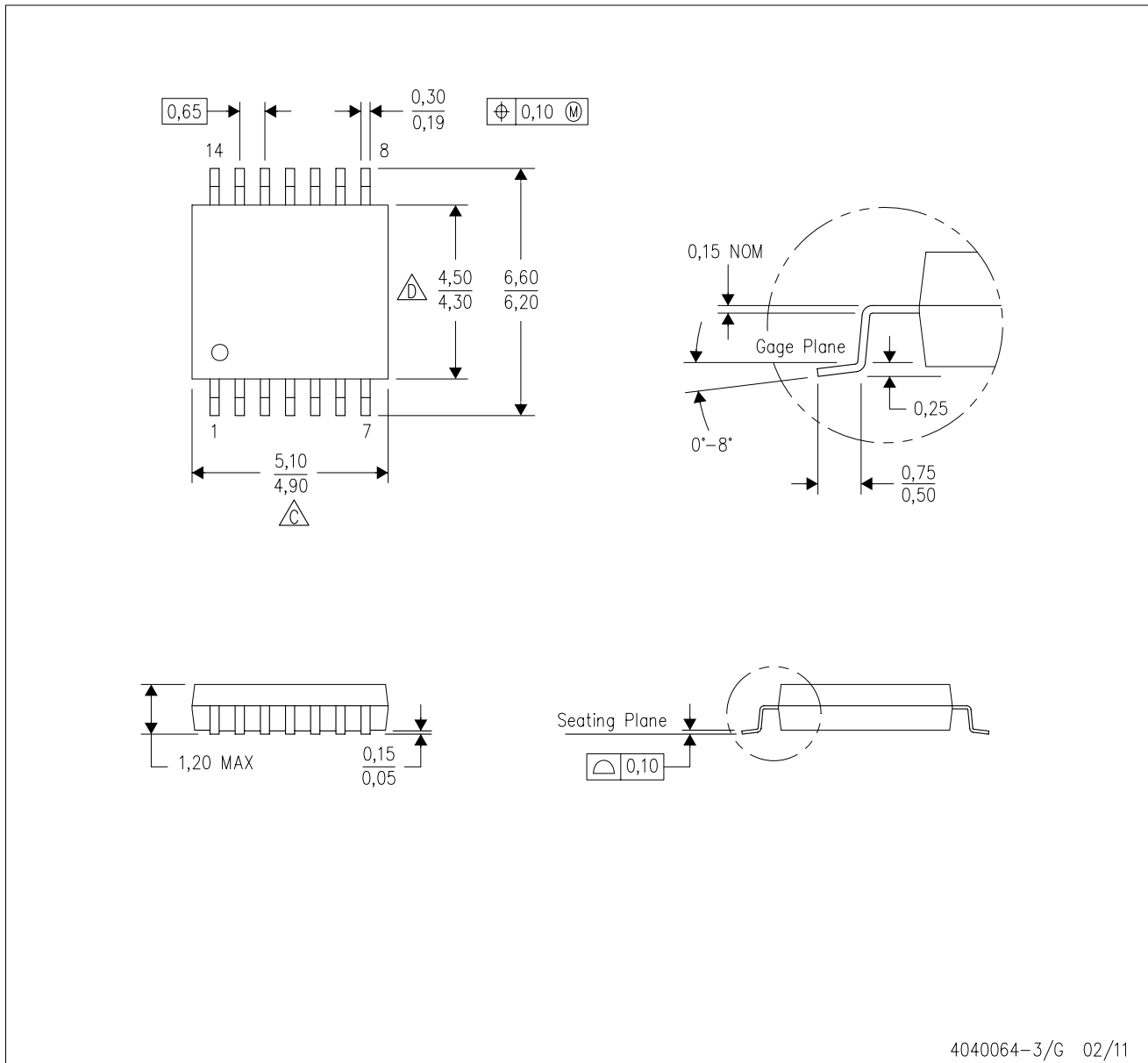
PLASTIC SMALL OUTLINE



- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Publication IPC-7351 is recommended for alternate designs.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
 - E. Falls within JEDEC MO-153



D0008A

PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed $.006$ [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

EXAMPLE BOARD LAYOUT

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
 EXPOSED METAL SHOWN
 SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

EXAMPLE STENCIL DESIGN

DBV0006A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214840/B 03/2018

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

DGS0010A



PACKAGE OUTLINE

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187, variation BA.

EXAMPLE BOARD LAYOUT

DGS0010A

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
SCALE:10X



SOLDER MASK DETAILS
NOT TO SCALE

4221984/A 05/2015

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DGS0010A

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:10X

4221984/A 05/2015

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale (www.ti.com/legal/termsofsale.html) or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2019, Texas Instruments Incorporated

Looking for pricing, stock, or lifecycle information?

Click below to explore more details on WIN SOURCE:

 [View TLV2621IDBVR on WIN SOURCE](#)

 [Texas Instruments](#) Information

Optimize Your Supply Chain with WIN SOURCE Solutions

-  Global Sourcing Solution
-  Obsolete Management
-  Cost Control Management
-  Shortage Management
-  Alternative Solution
-  Excess Inventory Management